

isc Triacs

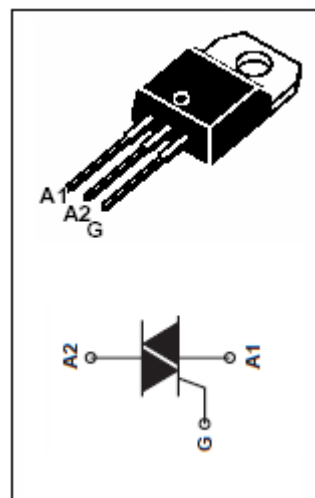
BTA08-600C

FEATURES

- With TO-220AB insulated package
- Suitable for general purpose applications where gate high sensitivity is required. Application on 4Q such as phase control and static switching.

ABSOLUTE MAXIMUM RATINGS($T_a=25^{\circ}\text{C}$)

SYMBOL	PARAMETER	MIN	UNIT
V_{DRM}	Repetitive peak off-state voltage	600	V
V_{RRM}	Repetitive peak reverse voltage	600	V
$I_{\text{T(RMS)}}$	RMS on-state current (full sine wave) $T_j=105^{\circ}\text{C}$	8	A
I_{TSM}	Non-repetitive peak on-state current $t_p=20\text{ms}$	80	A
T_j	Operating junction temperature	110	$^{\circ}\text{C}$
T_{stg}	Storage temperature	-45~150	$^{\circ}\text{C}$
$R_{\text{th(j-c)}}$	Thermal resistance, junction to case	2.5	$^{\circ}\text{C/W}$
$R_{\text{th(j-a)}}$	Thermal resistance, junction to ambient	60	$^{\circ}\text{C/W}$

ELECTRICAL CHARACTERISTICS ($T_c=25^{\circ}\text{C}$ unless otherwise specified)

SYMBOL	PARAMETER		CONDITIONS	MAX	UNIT
I_{RRM}	Repetitive peak reverse current		$V_R=V_{\text{RRM}}$, $V_R=V_{\text{RRM}}$, $T_j=110^{\circ}\text{C}$	0.01 0.5	mA
I_{DRM}	Repetitive peak off-state current		$V_D=V_{\text{DRM}}$, $V_D=V_{\text{DRM}}$, $T_j=110^{\circ}\text{C}$	0.01 0.5	mA
I_{GT}	Gate trigger current	I	$V_D=12\text{V}$; $R_L=30\ \Omega$	25	mA
		II		25	
		III		25	
		IV		50	
I_{H}	Holding current		$I_{\text{GT}}=0.1\text{A}$, Gate Open	25	mA
V_{GT}	Gate trigger voltage all quadrant		$V_D=12\text{V}$; $R_L=30\ \Omega$	1.3	V
V_{TM}	On-state voltage		$I_T=11\text{A}$; $t_p=380\ \mu\text{s}$	1.55	V